

长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech. Co., Ltd.

DATA SHEET

MDL-III-885R/1~400mW

INFRARED DIODE LASER AT 885nm

Diode infrared laser module at 885nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in measurement, communication, spectrum analysis, etc.



SPECIFICATIONS

Wavelength (nm)	885 ± 5			
Output power (mW)	>1, 50, 100, , 400			
Energy distribution	Even			
Beam Spot	Round			
Power stability (rms, over 4 hours)	<1%, <3%, <5%			
Warm-up time (minutes)	<5			
Beam divergence, full angle (mrad)	<8.0			
Dimensions of beam at the aperture (mm)	~2.0			
Beam height from base plate (mm)	24. 8			
Operating temperature (°C)	10~35			
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM	
Modulation option	TTL/Analog 1Hz-5KHz, 1Hz-10KHz, 1Hz-30KHz, and TTL on/off			
Expected lifetime (hours)	10000			
Warranty	1 year			





MxL-III-885R	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
139(L)×73(W) ×46. 2(H) mm³, 0.6kg	153 (L) ×155(W) ×92 (H) mm ³ , 1.5kg	133 (L) ×130(W) ×65 (H) mm ³ , 1.2kg	100 (L) ×62(W) ×56 (H) mm³, 0.2kg
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24.80 10.50 116 139		000100100	100 4-63.2